

**RECEIVED**  
**CENTRAL FAX CENTER**  
**JUN 29 2004**

**Patent**

Customer No.: 31561  
Docket No. 9893-US-PA  
Application No.: 10/605,084

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

In re application of

Applicant : Chen et al.  
Application No. : 10/605,084  
Filed : 2003/09/08  
For : POLYSILICON THIN FILM TRANSISTOR AND  
METHOD OF FORMING THE SAME  
Art Unit : 2826  
Examiner : ERDEM, FAZLI

**OFFICIAL****RESPONSE TO RESTRICTION REQUIREMENT**

ASSISTANT COMMISSIONER FOR PATENTS  
Arlington, VA 22202

Dear Sirs,

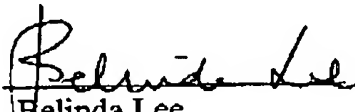
In response to the Office Action, mailed on June 10, 2004, Applicant would like to elect Group II, claims 4-8, drawn to method of making thin film transistor, class 438, subclass 149. Please cancel Group I, claims 1-3, drawn to thin film transistor, classified in class 257, subclass 347 without waiver, prejudice or disclaimer.

Thank you for your assistance in the subject matter. If you have any questions, please feel free to contact me.

Respectfully Submitted,  
JIANQ CHYUN IP Office

Date: June 29, 2004

By:

  
Belinda Lee  
Registration No.: 46,863

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